SURMOUNT™ 15µM PIN Diodes RoHS Compliant

Features

- 0603 Outline
- Surface Mount
- 15µm I-Region Length Devices
- No Wirebonds Required
- Silicon Nitride Passivation
- Polymer Scratch Protection
- Low Parasitic Capacitance and Inductance
- High Average and Peak Power Handling

Description

This device is a silicon, glass PIN diode surmount chip fabricated with M/A-COM Technology Solutions patented HMIC[™] process. This device features two silicon pedestals embedded in a low loss, low dispersion glass. The diode is formed on the top of one pedestal and connections to the backside of the device are facilitated by making the pedestal sidewalls electrically conductive. Selective backside metallization is applied producing a surface mount device. This vertical topology provides for exceptional heat transfer. The topside is fully encapsulated with silicon nitride and has an additional polymer layer for scratch and impact protection. These protective coatings prevent damage to the junction and the anode air-bridge during handling and assembly.

Applications

These packageless devices are suitable for usage in moderate incident power, ≤ 50 dBm/C.W. or where the peak power is ≤ 75 dBm, pulse width is $\leq 1\mu$ S, and duty cycle is $\leq 0.01\%$. Their low parasitic inductance, 0.4 nH, and excellent RC constant, make these devices a superior choice for higher frequency switch elements when compared to their plastic package counterparts.

Absolute Maximum Ratings¹ @T_{AMB} = +25°C (unless otherwise specified)

Parameter	Absolute Maximum
Forward Current	500 mA
Reverse Voltage	- 115 V
Operating Temperature	-55°C to +125°C
Storage Temperature	-55 °C to +150°C
Junction Temperature	+175°C
C.W. Incident Power	50dBm
Mounting Temperature	+280°C for 30 seconds

1) Exceeding these limits may cause in permanent damage

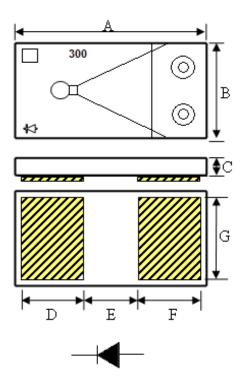
ADVANCED: Data Sheets contain information regarding a product MA-COM Technical Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product MA-COM Tech	nica	al
Solutions has under development. Performance is based on engineering tests. Specif		
tions are typical. Mechanical outline has been fixed, Engineering sand les and or test	dit	а
tions are typical. Mechanical outline has been fixed, Engineering same les and or tell may be available. Commitment to produce in rolling is not guar meet.		



Rev. V6

Case Style ODS 1314



Chip Dimensions

DIM	INC	HES	MM		
	Min	Max	Min	Max	
А	0.060	0.062	1.525	1.575	
В	0.031	0.032	0.775	0.825	
С	0.004	0.008	0.102	0.203	
D	0.019	0.021	0.475	0.525	
Е	0.019	0.021	0.475	0.525	
F	0.019	0.021	0.475	0.525	
G	0.029	0.031	0.725	0.775	

Notes:

- 1) Backside metal: 0.1microns thick.
- Yellow area with hatch lines indicate backside ohmic gold contacts.
- 3) Both devices have same outline dimensions (A to G).

• North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400 • India Tel: +91.80.43537383 • China Tel: +86.21.2407.1588

MADP-017015-1314 MADP-030015-1314

SURMOUNT™ 15µM PIN Diodes RoHS Compliant



Rev. V6

Parameter	Symbol	Conditions	Units	Min	Тур	Ma x	Min	Тур	Max
				MAI	DP-0170	15	MA	015	
Capacitance	CT	-40 V, 1 MHz ^{1,3}	pF		0.32	0.3 8		0.79	0.85
Capacitance	CT	-40V, 1 GHz ^{1,3}	pF		0.31			0.78	
Capacitance, 85°C	CT	-40 V, 1 GHz ^{1,3}	pF		0.29	0.29 0.7		0.76	
Resistance	Rs	+10 mA, 1 GHz ^{2,3}	Ω		0.72			0.49	
Resistance	Rs	+70 mA, 1 GHz ^{2,3}	Ω		0.51			0.38	
Resistance, 85°C	Rs	+10 mA, 1 GHz ^{2,3}	Ω		1.08			0.82	
Resistance, 85°C	Rs	+70 mA, 1 GHz ^{2,3}	Ω		0.84			0.69	
Forward Voltage	V _F	+10 mA	V		0.74	0.9 0		0.72	0.90
Reverse Leakage Current	I _R	-115 V	uA		-	10		-	10
Third Order Intercept Point	IP ³	F1= 1800 MHz F2 = 1810 MHz Input Power = 0 dBm I bias = +70 mA	dBc		-36.8			- 37. 0	
Thermal Resistance	θ		°C/W		30			13	
Lifetime	TL	+10 mA / -6 mA (50% - 90% V)	uS		1.3			1.6	

Electrical Specifications @ T_A = 25°C (unless otherwise noted)

Notes:

1) Total capacitance, C_T, is equivalent to the sum of Junction Capacitance ,Cj, and Parasitic Capacitance, Cpar.

2) Series resistance R_s is equivalent to the total diode resistance : Rs = Rj (Junction Resistance) + Rc (Ohmic Resistance)

3) Rs and C_T are measured on an HP4291A Impedance Analyzer with the die mounted in an ODS-186 package .

4) Theta (θ) is measured with the die mounted in an ODS-186 package .

Typical Spice Parameters @ $T_{AMB} = +25^{\circ}C$

Spice Parameter	Ν	RS	IS	IK	BV	IBV	Ct	CJO	٧J	Μ	FC	Cpar_Cj
Units	-	Ω	Α	(mA)	(Volts)	(μA)	(pF)	(pF)	(Volts)	-	-	(F)
MADP-017015-1314	1.1	1.2	9.8E-15	14.7	145	10	0.46	0.10	0.29	0.50	0.34	3.5E-13
MADP-030015-1314	1.1	1.1	8.5E-15	13.9	145	10	1.12	0.29	0.18	0.50	0.19	8.2E-13

ADVANCED: Data Sheets contain information regarding a product MA-COM Technical Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

teed. PRELIMINARY: Data Sheets contain information regarding a product MA-COM Technical Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed, Engineering sain, les and or tellt data

not guar

may be available. Commitment to produce

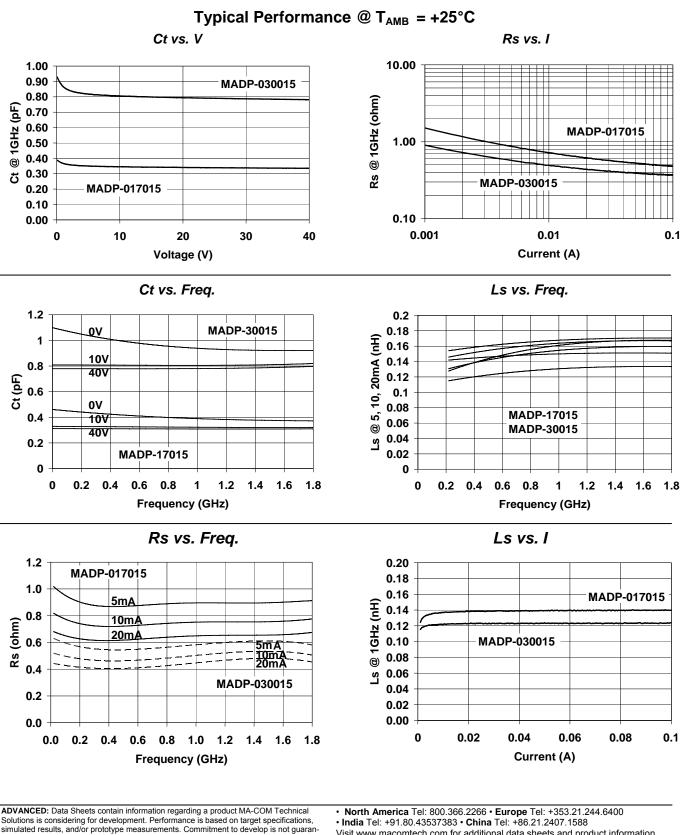
• North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400 • India Tel: +91.80.43537383 • China Tel: +86.21.2407.1588



MADP-017015-1314 MADP-030015-1314



SURMOUNT™ 15µM PIN Diodes **RoHS** Compliant



PRELIMINARY: Data Sheets contain information regarding a product MA-COM Technical Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering saint les and or test data may be available. Commitment to produce not guar

teed

MADP-017015-1314 MADP-030015-1314

SURMOUNT[™] 15µM PIN Diodes RoHS Compliant



Handling Procedures

All semiconductor chips should be handled with care to avoid damage or contamination from perspiration and skin oils. The use of plastic tipped tweezers or vacuum pickups is strongly recommended for individual components. Bulk handling should insure that abrasion and mechanical shock are minimized.

Bonding Techniques

Attachment to a circuit board is made simple through the use of surface mount technology. Mounting pads are conveniently located on the bottom surface of these devices and are removed from the active junction locations. These devices are well suited for solder attachment onto hard and soft substrates. The use of 80Au/20Sn, or RoHS compliant solders is recommended. For applications where the average power is ~1W, conductive silver epoxy may also be used. Cure per manufacturers recommended time and temperature. Typically 1 hour at 150°C.

When soldering these devices to a hard substrate, hot gas die bonding is preferred. A vacuum tip pick-up tool and a force of 60 to100 grams applied to the top surface of the device is recommended. When soldering to soft substrates, such as Duroid, it is recommended to use a soft solder at the circuit board to mounting pad interface. Position the die so that its mounting pads are aligned with the circuit board mounting pads. While applying a downward force perpendicular to the top surface of the die, apply heat near the circuit trace and diode mounting pad. The solder connection to the two pads should not be made one at a time as this will create unequal heat flow and thermal stress to the part. Solder reflow should not be performed by causing heat to flow through the top surface of the die to the back. Since the HMIC glass is transparent, the edges of the mounting pads can be visually inspected through the die after attachment is completed.

Typical re-flow profiles for Sn60/Pb40 and RoHS compliant solders is provided in <u>Application Note M538</u>, "Surface Mounting Instructions" and can viewed on the MA-COM website @ <u>www.macomtech.com</u>

Ordering Information

Gel Pack

MADP-017015-13140G

MADP-030015-13140G

ADVANCED: Data Sheets contain information regarding a product MA-COM Technical Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product MA-COM Technical Solutions has under development. Performance is based on engineering tests, Specifications are typical. Mechanical outline has been fixed. Fingineering sant les and or te t data may be available. Commitment to produce Aryoure stop guar measured. North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400
India Tel: +91.80.43537383 • China Tel: +86.21.2407.1588
Vicit www.macowtook.com for additional data abacta and aradust information

